

BSC048N025S G

Request a Quote

BSC048N025S G Information

		BSC048N025S G Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
THE PROPERTY	Description Package	MOSFET N-CH 25V 89A TDSON-8 8-PowerTDFN	
For Reference Only		For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSC048N025S G Specifications

Manufacturer Part Number	BSC048N025S G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	25V
Current - Continuous Drain (Id) @ 25°C	19A (Ta), 89A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 35µA
Gate Charge (Qg) (Max) @ Vgs	21nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	2670pF @ 15V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.8W (Ta), 63W (Tc)
Rds On (Max) @ Id, Vgs	4.8 mOhm @ 50A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

BSC048N025S G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC048N025S G Payment Methods





If you have any question about BSC048N025S G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com